Product data sheet

1. General description

EEPP[™]- Efficiency Enhanced Pt Planar rectifier in a TO247-2L plastic package.

2. Features and benefits

- Fast switching
- · Reduces switching losses with improved lower reverse recovery charge
- Soft recovery characteristics
- Low thermal resistance
- · Low leakage current
- Planar termination structure
- High operating temperature capability (T_{i (max)} = 175°C)
- Higher I_{FSM} capability

3. Applications

- · Switched-Mode Power Supplies
- Power factor correction diode
- Uninterrupted Power Supply

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Values			Unit	
Absolute maximum rating							
V_{RRM}	repetitive peak reverse voltage			1200			V
I _{F(AV)}	average forward current	$δ = 0.5$; square-wave pulse; $T_{mb} \le 80$ °C; Fig. 1; Fig. 2; Fig. 3		60			А
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t_p = 25 μ s; $T_{mb} \le 80$ °C; square-wave pulse		1	20		А
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	500			А	
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse;	550		А		
Symbol	Parameter	Conditions	Min Typ Max		Unit		
Static ch	aracteristics						
V _F	forward voltage	I _F = 60 A; T _j = 25 °C; <u>Fig. 6</u>		-	2.8	3.3	V
		I _F = 60 A; T _j = 150 °C; <u>Fig. 6</u>		-	2.2	-	V
Dynamic	characteristics						
t _{rr}	reverse recovery time	ery time $I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A}/\mu\text{s}$; $-$ 55 $ T_j = 25 ^{\circ}\text{C}$; Fig. 7		ns			
Avalanche energy							
E _{AS}	non-repetitive avalanche energy	$T_{j(init)} = 25 ^{\circ}C$		50	-	-	mJ

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	N°0°4	K — A
2	Α	anode	ψOq	001aaa020
mb	mb	mounting base; connected to cathod	o K A TO247-2L	

6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BYC60W-1200P	TO247-2L	Plastic single-ended through-hole package; heatsink mounted;1 mounting hole; 2 leads TO-247	TO247A-2L			

7. Marking

Table 4. Marking codes

Type number	Marking codes
BYC60W-1200P	BYC60W-1200P

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		1200	V
V_{RWM}	crest working reverse voltage		1200	V
V_R	reverse voltage	DC	1200	V
I _{F(AV)}	average forward current	$δ = 0.5$; square-wave pulse; $T_{mb} \le 80$ °C; Fig. 1; Fig. 2; Fig. 3	60	А
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 μs; T _{mb} ≤ 80 °C; square-wave pulse	120	Α
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	500	А
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse;	550	Α
T _{stg}	storage temperature		-65 to 175	°C
T _j	junction temperature		175	°C

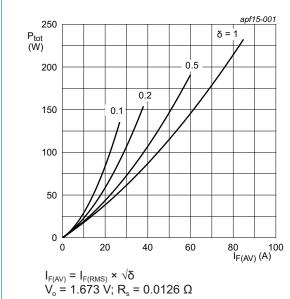
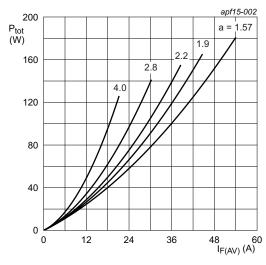
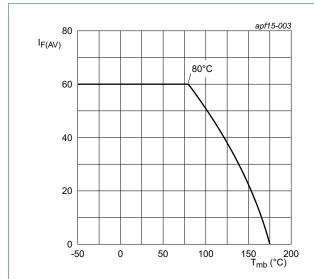


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor = $I_{F(RMS)}/I_{F(AV)}$ Vo = 1.673 V; Rs = 0.0126 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values





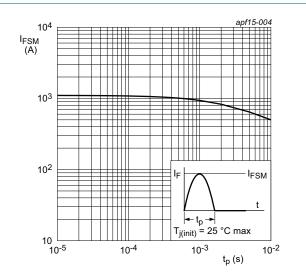
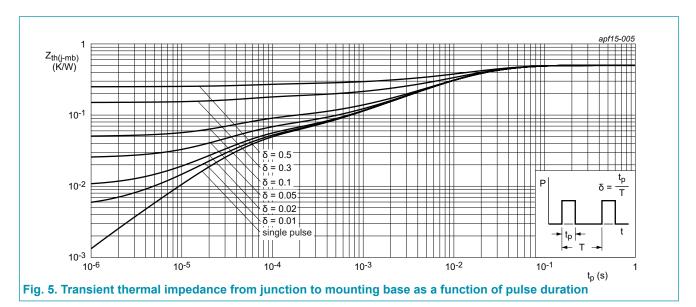


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

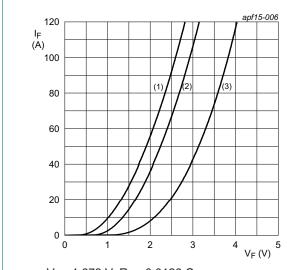
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 5</u>	-	-	0.5	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	45	-	K/W



10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
V_{F}	forward current	I _F = 60 A; T _j = 25 °C; <u>Fig. 6</u>	-	2.8	3.3	V
		I _F = 60 A; T _j = 150 °C; <u>Fig. 6</u>	-	2.2	-	V
I _R	reverse current	V _R = 1200 V; T _j = 25 °C	-	-	250	μA
		V _R = 1200 V; T _j = 150 °C	-	-	2	mA
Dynamic	characteristics					
Q _r	reverse charge	$I_F = 50 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	952	-	nC
		$I_F = 50 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$	-	2920	-	nC
		$I_F = 50 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 150 \text{ °C}; Fig. 7$	-	3425	-	nC
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	55	-	ns
		$I_F = 50 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	96	-	ns
		$I_F = 50 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$	-	194	-	ns
		$I_F = 50 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 150 \text{ °C}; Fig. 7$	-	212	-	ns
I _{RM}	peak reverse recovery current	$I_F = 50 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	20	-	А
		$I_F = 50 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_i = 125 \text{ °C}; Fig. 7$	-	30.2	-	А
		I _F = 50 A; V _R = 400 V; dI _F /dt = 500 A/μs; T _i = 150 °C; <u>Fig. 7</u>	-	32.3	-	А
Avalanch	ne energy		J		<u> </u>	
E _{AS}	non-repetitive avalanche energy	T _{j(init)} = 25 °C	50	-	-	mJ



 V_o = 1.673 V; R_s = 0.0126 Ω

(1) T_j = 150 °C; typical values (2) T_j = 150 °C; maximum values

(3) T_j = 25 °C; maximum values Fig. 6. Forward current as a function of forward voltage

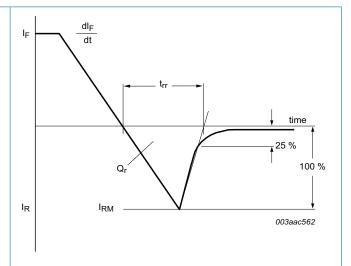
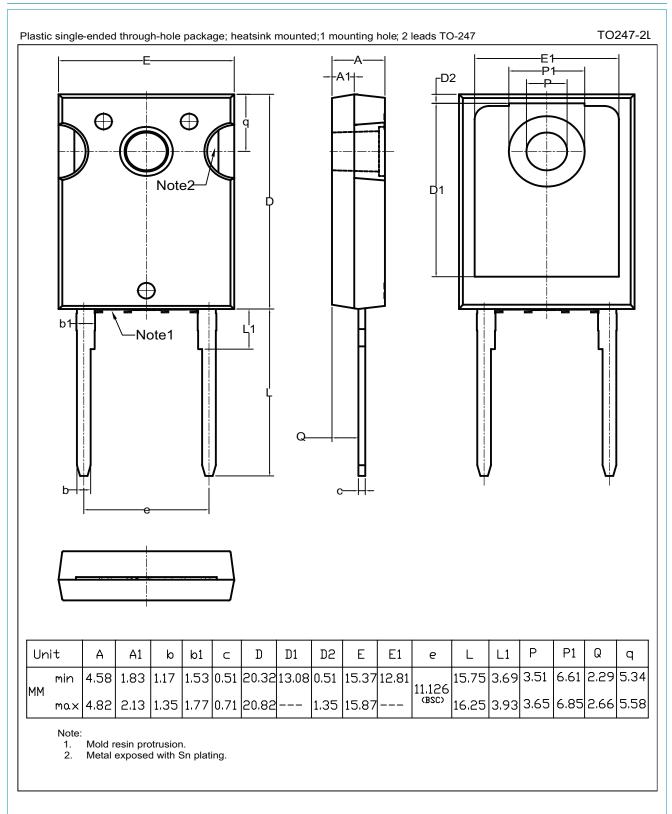


Fig. 7. Reverse recovery definitions; ramp recovery

11. Package outline



BYC60W-1200P

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Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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